

Performance Analysis of Solar Grade Crystalline Silicon Modules

Genmao Chen and Shawn Qu

IPRW II, Phoenix, July 2009

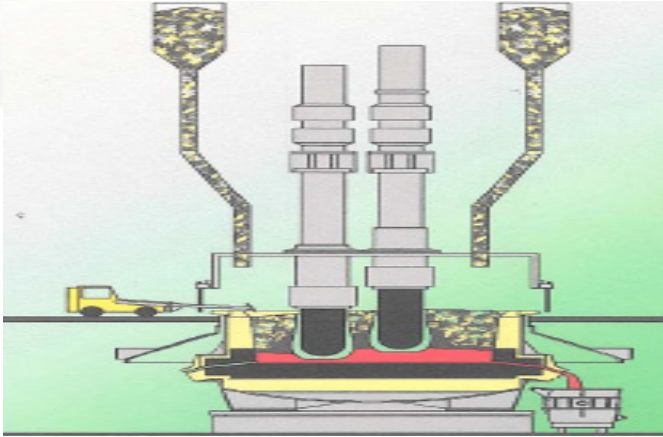
Performance Analysis of Solar Grade Crystalline Silicon Modules

OUTLINE

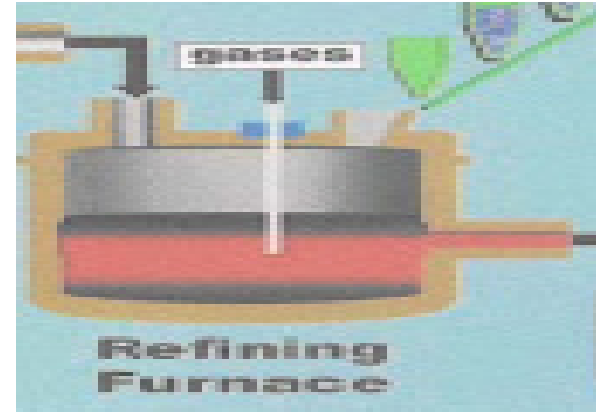
- **Solar grade Si vs. Conventional Poly-Si**
- **Comparison between solar grade and conventional crystalline Si solar modules**
 - **Wafer impurities**
 - **Reverse breakdown voltage and hot spots**
- **e-Module and its power station performance data**
 - **Comparison with conventional module power station**
 - **Initial light induced degradation**
 - **Long term performance**
- **Summary**

Typical Solar Grade Silicon Process

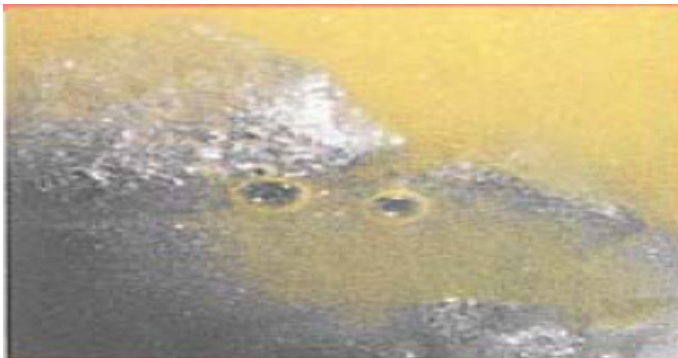
Arc Furnace



Slag Treatment



Chemical Leaching

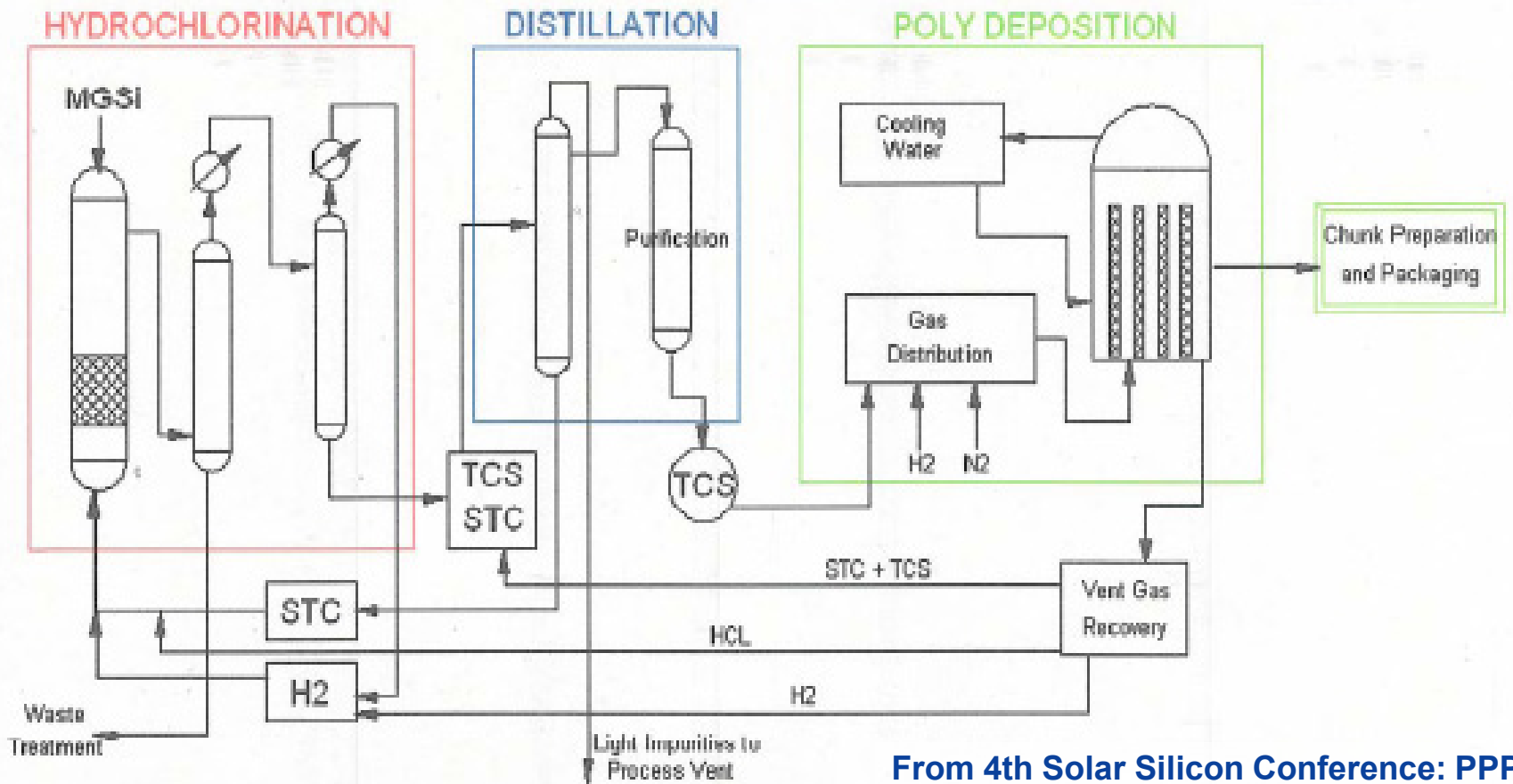


Solidification and Sorting



Solar grade Si: environmental friendly manufacturing

Modified Siemens Type Poly Silicon Process



Siemens Type: by-products with environmental concerns

Solar Grade Si vs. Conventional Poly Si

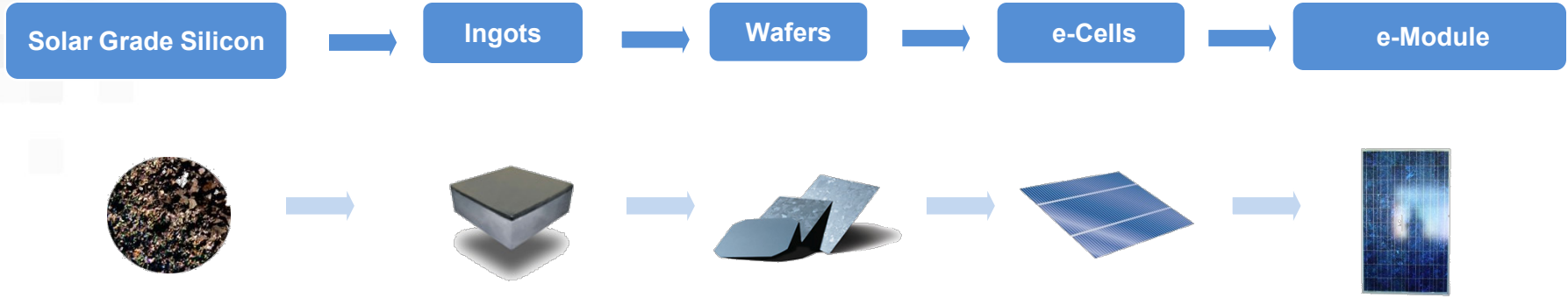
	Conventional poly-Si	Solar grade Si
Energy consumption (KWh/kg)	80-200	10-20
Environmental impact	High	Very low
Impurity levels* of currently available commercial supply	1) 6N-7N, 7N-8N; 2) 8N-9N; 3) better than 9N	5N- ~6N
Product cost (\$/kg)	30-60	10-25
Investment \$(USD)M/1000MT	~100	~15
Factory construction period	~2Years	<1Year
Typical multi-crystalline cell efficiency	15-16.5%	14-15.5%

Solar grade Si: Low cost, fast energy payback, environmentally friendly

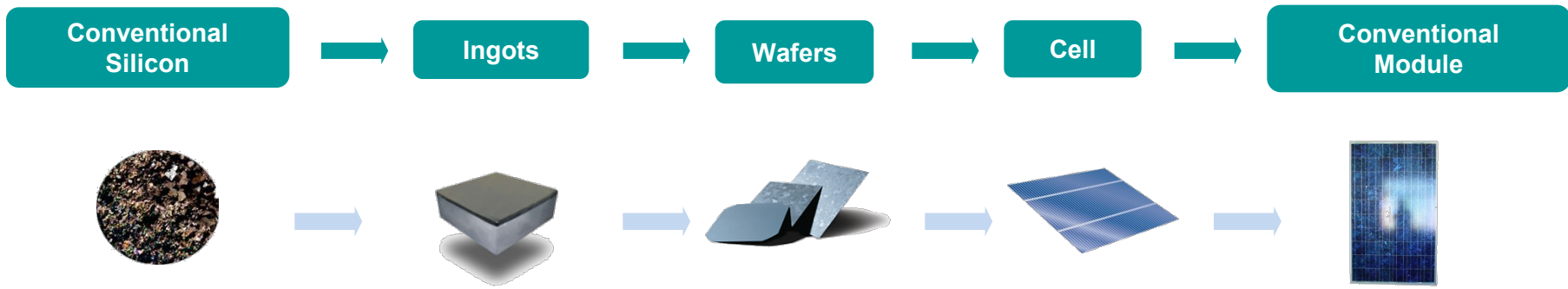
* Not including O and C

Manufacturing: e-Modules vs. Conventional

e-Modules



Conventional Modules



Same production equipment, enhanced processing

SIMS Wafer Impurity Analysis

Sample ID.	C	O	Al	Cr	Fe
N-A (at/cm ³)	4.18E+17	1.01E+17	3.16E+13	<	<
U-C (at/cm ³)	3.86E+17	1.13E+17	1.34E+14	<	<
Detection limits	2.00E+16	5.00E+16	1.00E+13	2.00E+13	1.00E+14
Threshold con. *			4.40E+15	1.30E+14	2.50E+14
Sample ID.	Mn	Ni	Cu	Ca	Ti
N-A (at/cm ³)	<	<	<	<	<
U-C (at/cm ³)	<	<	<	<	<
Detection limits	1.00E+13	2.00E+14	1.00E+14	1.00E+13	5.00E+12
Threshold con. *	1.80E+14	5.00E+15	4.10E+17	-	2.60E+12

* Threshold concentration defined as the impurity level where the impact to cell performance becomes explicit

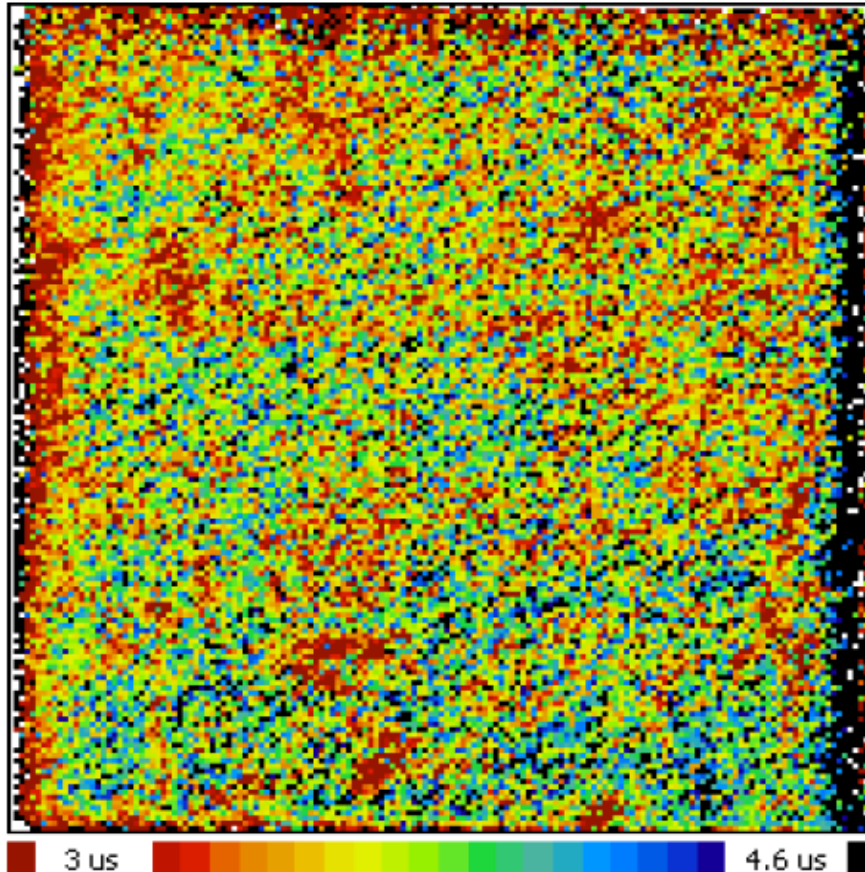
Source : Davis *et al.*, Impurities in Silicon Solar Cells

N-A: Conventional mc-wafer (from one of the main wafer suppliers)

U-C: Solar grade mc-wafer from Canadian Solar

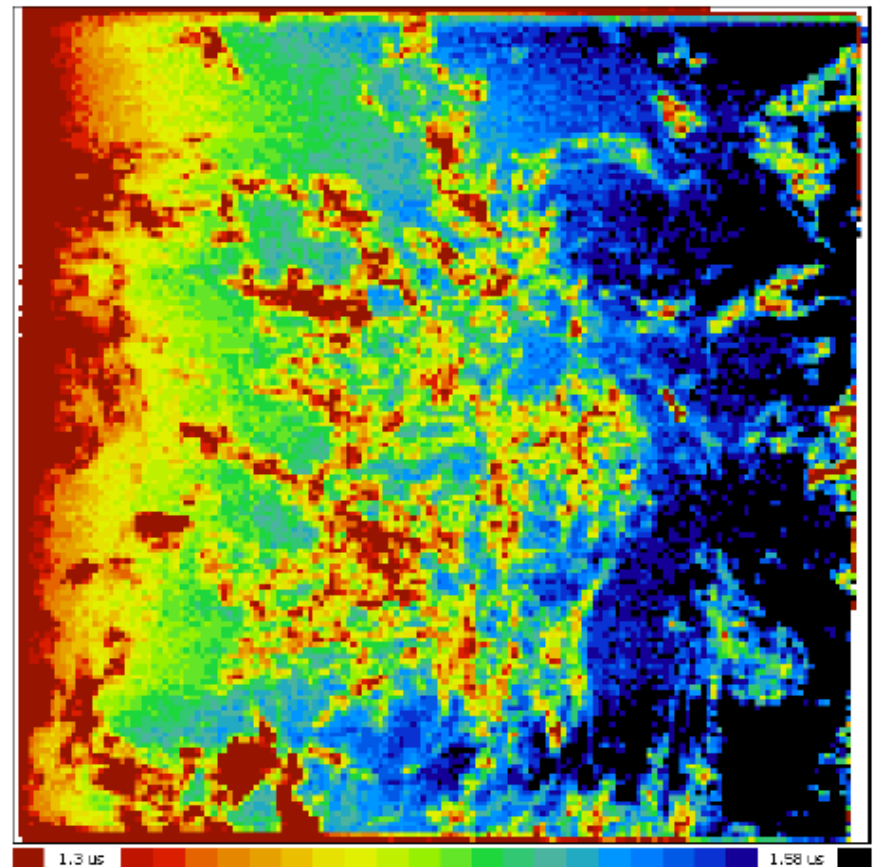
Wafer Minority Carrier Lifetime Mapping

(Without Passivation)



Scale 3.0 - 4.6 us

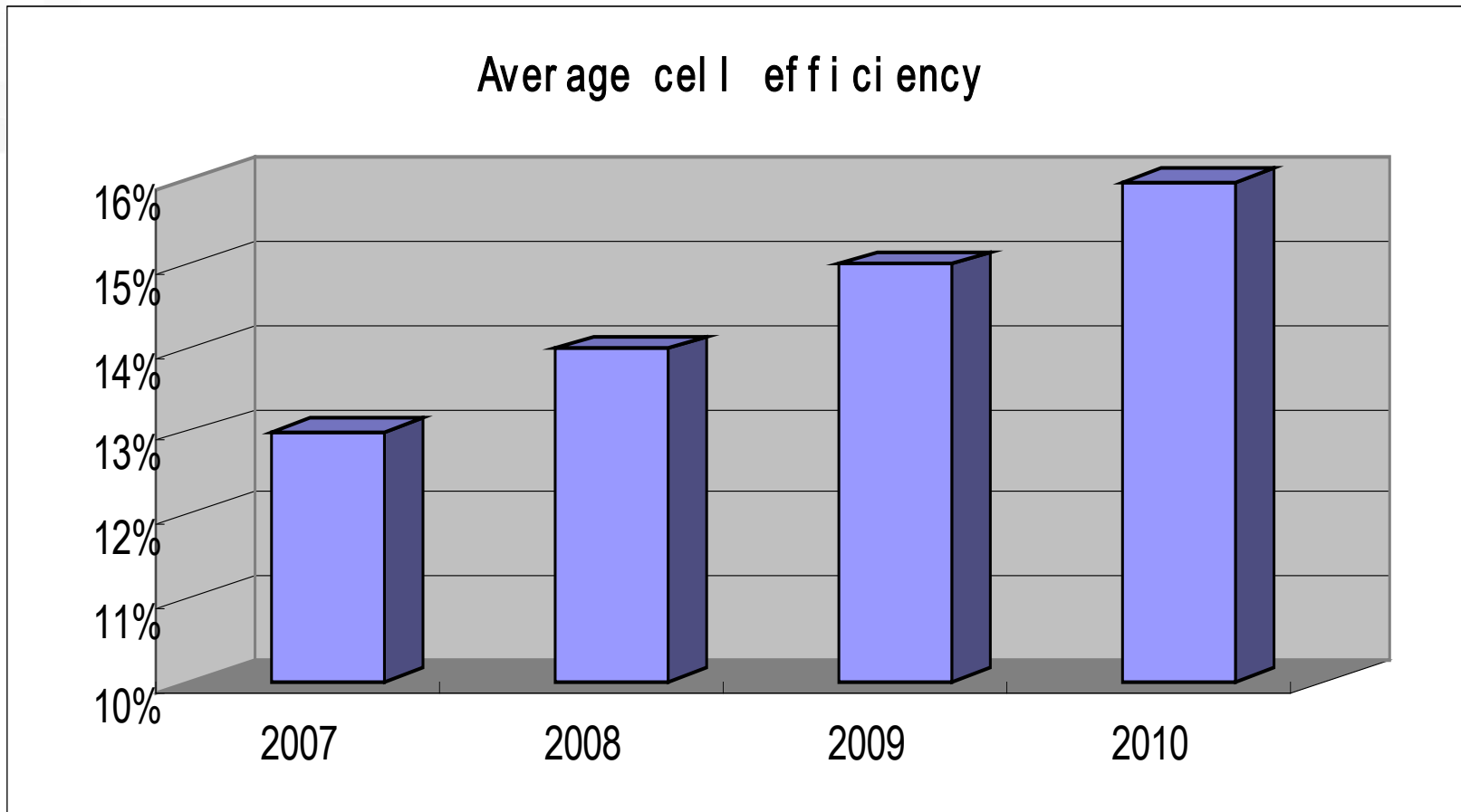
SoG Si mc-wafer lifetime mapping



Scale 1.3 - 1.58 us

Conventional Si mc-wafer lifetime mapping

Solar Grade Si Cell Efficiency Footprint & Roadmap



SoG Si cell efficiency will catch up the conventional Si cell efficiency in next 2-3 years

The relatively low reverse breakdown voltage of SoG Si cells is well addressed through:

- ❑ **Materials:** multiple DSS has greatly reduced the metal impurity levels
- ❑ **Growth process:** Specially designed ingot growth process has improved wafer crystal quality
- ❑ **P-gettering process:** Specially designed P-gettering process reduces impurity level and improves cell quality
- ❑ **Control:** Strict cell sorting and specially designed diode configurations keep e-Module performing as reliable as conventional modules

Hot Spots Testing



Single day outdoor hot spots testing



Long term hot spots testing on roof

e-Modules perform normally even over long-term testing

Performance of e-Modules

Causes of initial degradation:

- Cell passivation degradation
- Light induced degradation (LID)
- In some cases: Initial exposure of glass to sunlight can cause an increase of IR absorption

Initial performance results:

- Typically LID for SoG modules is 2-4%; stabilized after 3-4 days
- Higher than the initial LID of conventional modules (~1-2%)
- LID mainly caused by B-O complex; LID results in a reduction of Isc
- e-Module flashing is adjusted at factory to compensate the LID

Long Term Performance of e-Modules

Isc slow decreasing	FF decreasing
<ul style="list-style-type: none"> ▪ Front side delamination ▪ EVA discoloration ▪ Hot spots cause EVA yellowing spots ▪ Back-side delamination interrupts the heat dissipation and causes the hot spots 	<ul style="list-style-type: none"> ▪ Thermal stress induced micro-cracking under ribbon ▪ Delamination caused the hot spots which, in turn, result in micro-cracking under ribbon ▪ Moisture intrusion cause the finger or busbar corrosion ▪ J-box connection corrosion and resistance increasing

	Module-1	Module 2	Module 3	Module 4	Module 5	Module 6	Module 7	Module 8
Pmax(W)*	180.1	189.3	190.16	178.3	177.8	184.94	193.8	190
Pmax(W)**	179.71	188.25	188.2	178.07	175.65	184.69	192.17	189.34
Pmax change	-0.22%	-0.56%	-1.03%	-0.10%	-1.21%	-0.13%	-0.84%	-0.35%

Annual change rate is -0.56%

* Tested after 1 week LID

** Tested after 1y operation in power station

Performance Comparison

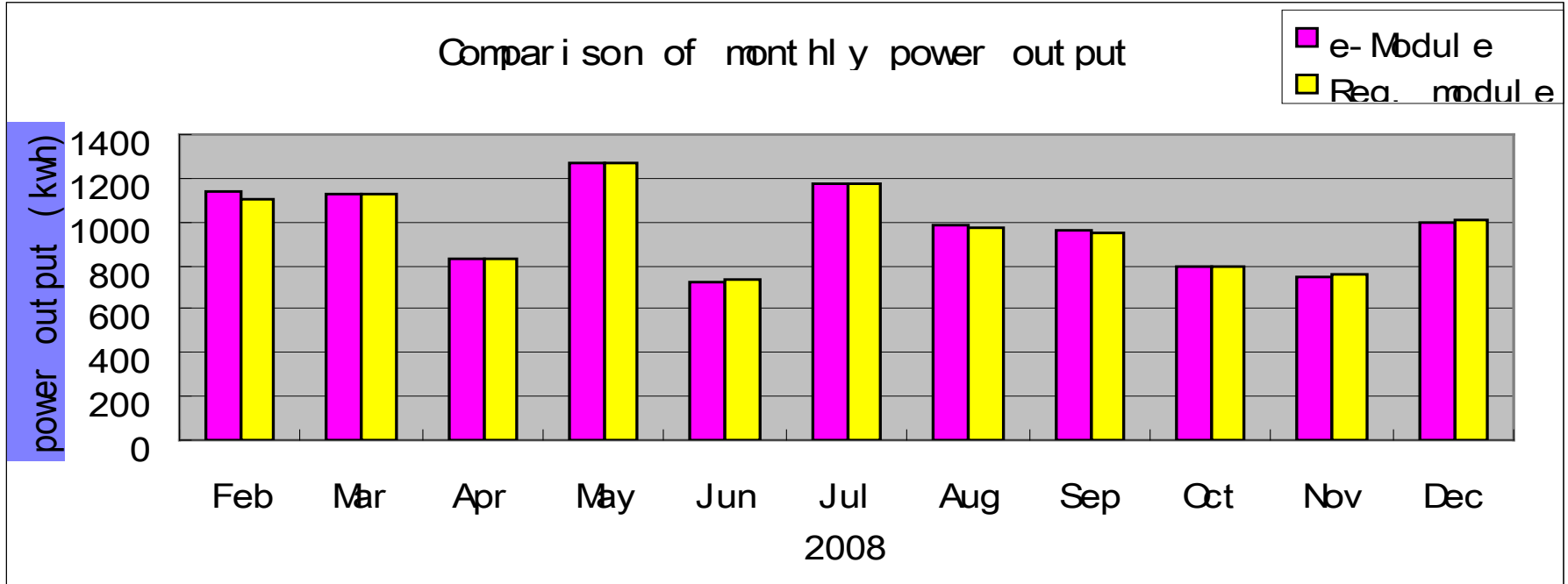
e-Modules



Conventional Modules

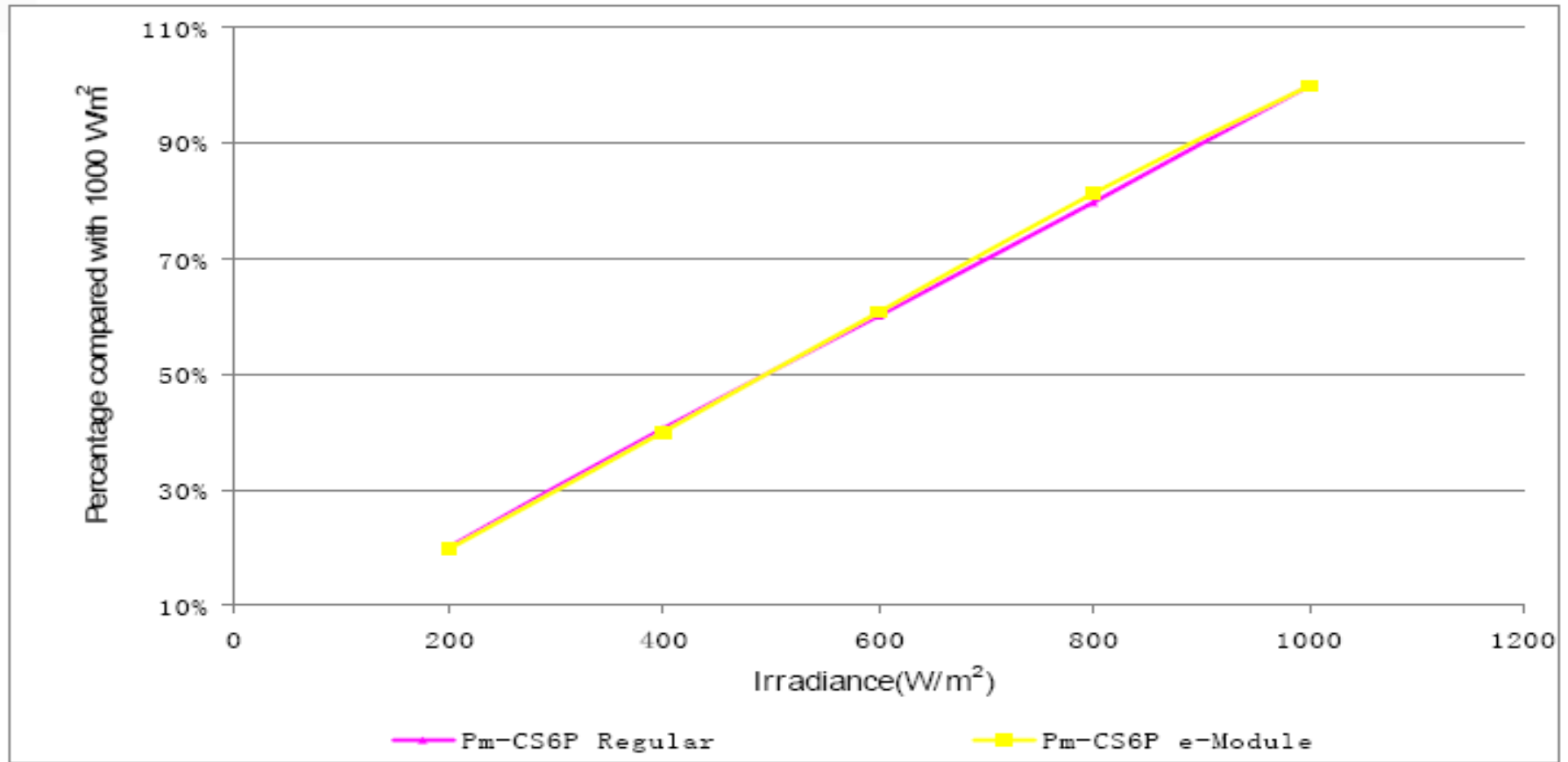


Comparison of monthly power output



Equal performance to conventional modules, BETTER at high temperatures (peak pricing periods)

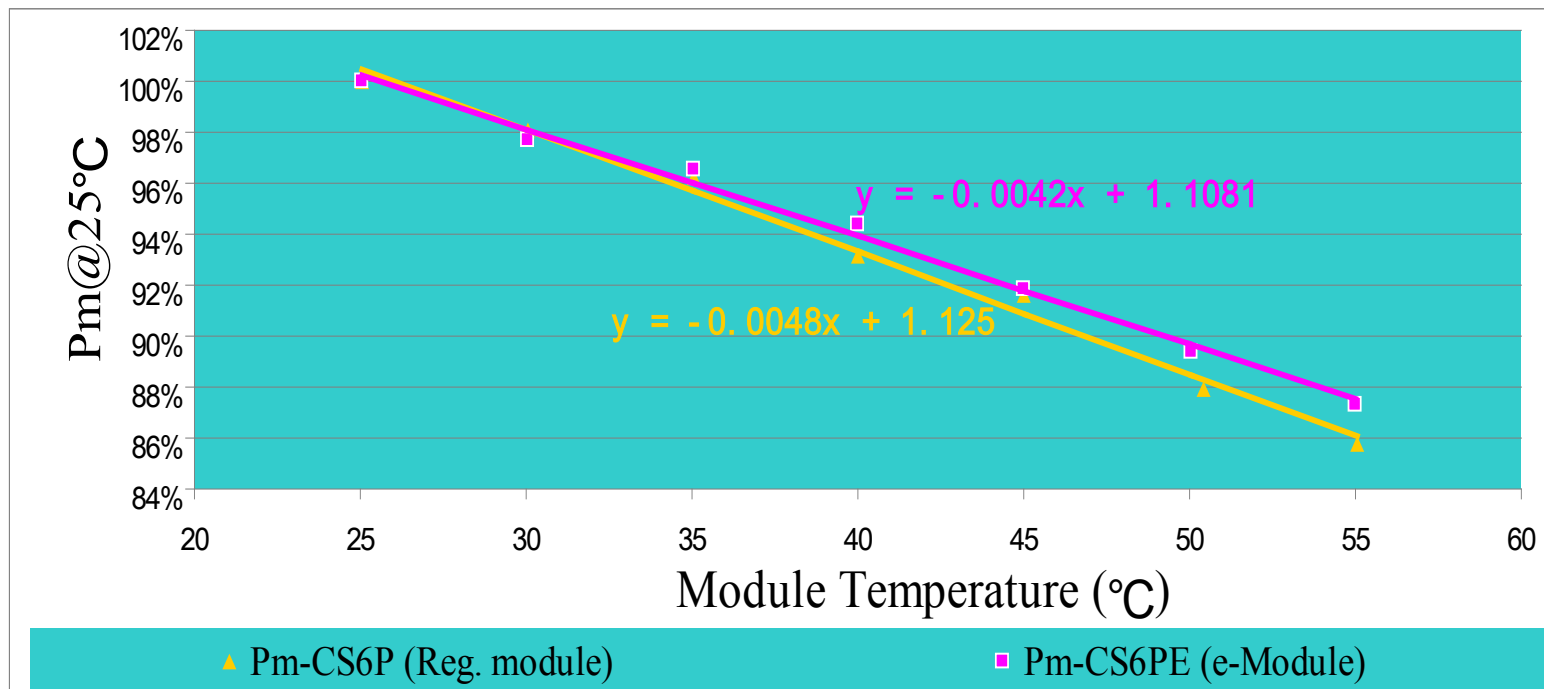
System Output vs. Irradiation



Equal performance to conventional modules

Modules Temperature Coefficients

	α -Isc(%/°C)	β -Voc(%/°C)	γ -Pm(%/°C)
CS6P Reg. module	0.073%	-0.356%	-0.494%
CS6PE e-Module	0.107%	-0.378%	-0.438%



A lower peak power temperature coefficient

Activities on Long Term e-Module Performance



- **A new e-Module power station (shown above) built in Dec. 2008 to monitor the long term performance of the new e-Module products**
- **12 e-Modules and 6 conventional modules were sent to PTL (now part of TUV group) for long term performance analysis**
- **Canadian Solar tracks long term performance for selected e-Module solar projects built all over world**

Summary

- ❑ SoG Si: low cost, fast energy payback time, and environmental friendly
- ❑ e-Modules demonstrate long term performance equivalent to conventional modules
- ❑ e-Modules demonstrate similar annual degradation rates as conventional modules (approx. -0.56%)
- ❑ e-Modules demonstrate excellent potential for fast-pace efficiency improvement and cost reduction
- ❑ **With performance on par with conventional silicon modules, e-Module will be the first crystalline silicon module to reach thin film price**



Super-highway to Grid Parity

Canadian Solar works hard to build the solar super-highway to Grid Parity

e-Module Project in USA



Project Details

Location	Visalia, CA	Module Type	e-Module CS6P-PE
System Size	392.645 kWp	Completion	August 2008

e-Module Project in Germany



Project Details

Location	Ostfriesland, Germany	Module Type	e-Module CS6A-PE
System Size	111 KWp	Completion	September 2008

e-Module Project in Korea



Project Details

Location	Jeong Up-si, Korea	Module Type	e-Module CS6P-PE
System Size	300 KWp	Completion	September 2008



Thank you !